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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/820,476	04/08/2004	Peter J. Hopper	100-18110 (P05269-D01)	8696	
33402	7590 10/31/2005		. EXAMINER		
LAW OFFICES OF MARK C. PICKERING			NGUYEN, TUAN H		
P.O. BOX 30 PETALUMA	-		ART UNIT	PAPER NUMBER	
			2813		

DATE MAILED: 10/31/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

			1 m			
	Application No.	Applicant(s)	X			
	10/820,476	HOPPER ET AL.				
Office Action Summary	Examiner	Art Unit				
	Tuan H. Nguyen	2813				
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet	t with the correspondence addi	ress			
A SHORTENED STATUTORY PERIOD FOR REPL' WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period value and the second period for reply within the set or extended period for reply will, by statute any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMU 36(a). In no event, however, may will apply and will expire SIX (6) No. cause the application to become	NICATION. y a reply be timely filed MONTHS from the mailing date of this come a ABANDONED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 23 A	<u>ugust 2005</u> .					
2a) ☐ This action is FINAL . 2b) ☑ This	This action is FINAL . 2b)⊠ This action is non-final.					
• •	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under E	Ex parte Quayle, 1935 (C.D. 11, 453 O.G. 213.				
Disposition of Claims						
4)⊠ Claim(s) <u>7-13 and 17-27</u> is/are pending in the	application.					
4a) Of the above claim(s) is/are withdraw	4a) Of the above claim(s) is/are withdrawn from consideration.					
5) Claim(s) 7-13 is/are allowed.						
6)⊠ Claim(s) <u>17,19 and 27</u> is/are rejected.	Claim(s) <u>17,19 and 27</u> is/are rejected.					
7) Claim(s) 18 and 20-26 is/are objected to.						
8) Claim(s) are subject to restriction and/o	r election requirement.					
Application Papers						
9) The specification is objected to by the Examine	er.					
10) The drawing(s) filed on is/are: a) □ acc	epted or b) ☐ objected	to by the Examiner.				
Applicant may not request that any objection to the						
Replacement drawing sheet(s) including the correct						
11) The oath or declaration is objected to by the Ex	caminer. Note the attac	ned Office Action or form PTC)-152.			
Priority under 35 U.S.C. § 119						
12) ☐ Acknowledgment is made of a claim for foreign a) ☐ All b) ☐ Some * c) ☐ None of:		C. § 119(a)-(d) or (f).				
 Certified copies of the priority document Certified copies of the priority document 		n Application No				
3. Copies of the certified copies of the prior			tage			
application from the International Burea						
* See the attached detailed Office action for a list		not received.				
Attachment(s)						
1) Notice of References Cited (PTO-892)		ew Summary (PTO-413)				
 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 9/12/05. 		No(s)/Mail Date of Informal Patent Application (PTO- 	152)			

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 8/23/05 has been entered.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 17, 19, 27 are rejected under 35 U.S.C. 102(e) as being anticipated by U.S. Pat. No. 6,413,832 to Wu et al. (cited ref.).

Wu et al., figs. 1-5 and text on col. 3-4 teaches the claimed method for forming a semiconductor device on an insulation region including: forming a trench 24 in the insulation region 12, 14, 16, the trench 24 having a side wall surface and a bottom surface, the side wall surface extending continuously from the top surface to the bottom surface and exposing only the insulation region 12 (fig. 3); forming a layer 32 of

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conductive material on the insulation region 12 to contact the trench; etching the layer 32 of conductive material to form an opening and a conductive spacer that contacts the side wall surface; and forming a layer 42 of isolation material on the insulation region 12 and conductive spacer 32 to contact the opening (fig. 4, col. 3, last paragraph to col. 4, first paragraph).

With respect to claims 19, 21, fig. 5 shows the step of etching the layer of isolation material to form a hole, exposed bottom surface of the trench, and an isolation spacer 42 that contacts a side wall of the conductive spacer 32; and forming a layer of conductive material on the insulation region 12,the conductive spacer 32, and the isolation spacer 42 to contact the hole (fig. 5).

Allowable Subject Matter

Claims 7-13 are allowed.

Claims 18, 20-26 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter: None of the references of record teaches or suggests the claimed method form forming a semiconductor device including the step of forming a conductive region making an electrical connection with the first conductive spacer as recited in claim 7, 18, 20, 23-26; or forming a layer of insulation material on the interior spacer to contact the aperture as recited in claims 21, 22.

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tuan H. Nguyen whose telephone number is 571-272-1694. The examiner can normally be reached on 9AM-5:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead Jr. can be reached on 571-272-1702. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Tuan H- Nguyen Tuan H. Nguyen Primary Examiner Art Unit 2813